

**TONE DECODER IC**

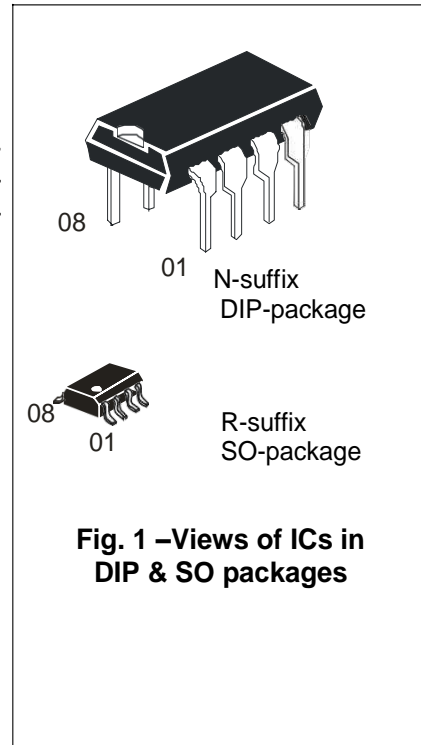
The HT567 are general purpose tone decoders .

ICs are purposed to receive and decode sine signal of wide bandwidth in telecom systems.

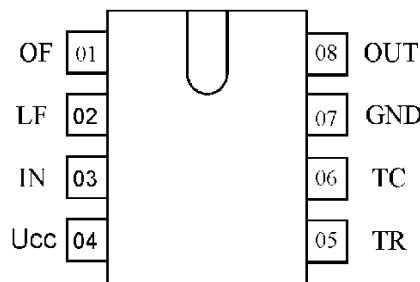
IC can be applied for tone (voice-frequency) decoding, frequency control, broadband FSK demodulations, ultrasonic frequency control, in precision generator, search decoders.

**Main features**

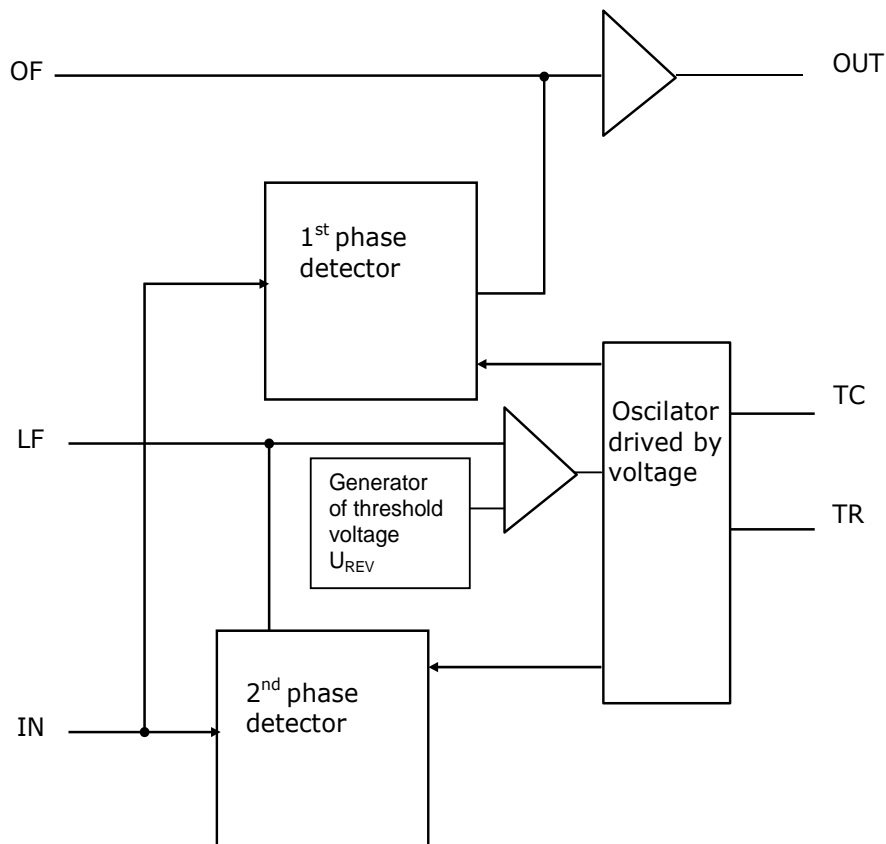
- Bandwidth, BW, %  
 (relatively to central frequency  $f_c$ )  
 min.....10;  
 max.....18;
- Bandwidth central frequency,  $f_c$ , kHz  
 min.....100;  
 (at  $U_{CC} = 5\text{ V}$ ,  $R = 2,8\text{ k}\Omega$ ,  $C = 3300\text{ pF}$ )  
 max.....500;  
 (at  $U_{CC} = 5\text{ V}$ ,  $R = 2,8\text{ k}\Omega$ ,  $C = 800\text{ pF}$ )  
 Center frequency adjustable from 0,01Hz to 500 kHz.
- Quiescent consumption current,  $I_{CC}$ , mA  
 (at  $U_{CC} = 5\text{ V}$ ,  $R_L = 20\text{ k}\Omega$ ),  
 not more .....8;
- Operating temperature range 0 to +70°C;
- Immunity to ESD potential 200 V. Limiting value of the potential of static electricity 350 V;
- Logic compatible output with 100mA current sinking capability;
- High rejection of outband signals and noise;
- Thermal resistance «junction-ambient»  
 for HT567AN not more 110 °C/W;  
 for HT567AR not more 160 °C/W.



**Fig. 1 –Views of ICs in DIP & SO packages**



**Fig. 2 – Pinout diagramm**


**Fig. 3 – Block diagram of IC**
**Table 1 – Pin description**

Pin number	Symbol	Description
01	OF	Filter output
02	LF	Loop filter (Low frequency filter of the synchronous demodulator)
03	IN	Detected frequency input
04	$U_{CC}$	Supply voltage pin
05	TR	Timing resistor connection pin
06	TC	Timing capacitor connection pin
07	GND	Common pin (Ground)
08	OUT	Output

**Table 2 – Absolute maximum ratings**

Symbol	Parameter	Norm		Unit
		Min	Max	
U <sub>CC</sub>	Supply voltage	-	9,5	V
U <sub>03</sub>	Input voltage (pin 03)	-10	U <sub>CC</sub> +0,5	V
P <sub>tot</sub> <sup>1)</sup>	Total power dissipation	-	1100 <sup>2)</sup>	mW
T <sub>a</sub>	Storage temperature	-50	125	°C

<sup>1)</sup>At IC operation junction temperature has not to exceed 115 °C taking into account thermal resistance "junction-ambient". For HT567AN thermal resistance "junction-ambient" - 110 °C/W. For HT567AR thermal resistance "junction-ambient" - 160 °C/W.  
 Maximum power P<sub>tot</sub>,W, dissipated by IC for T<sub>A</sub>, is calculated by formula

$$P_{tot} = (115 - T_A) / R_{TJA}, \quad (1)$$

115 – maximum permissible operating junction temperature, °C;  
 T<sub>A</sub> – ambient temperature, °C;  
 R<sub>TJA</sub> – thermal resistance «junction-ambient», °C/W.

<sup>2)</sup>Duration of influence of extreme mode has to be not more than 20 ms

**Table 3 – Recommended operation modes**

Symbol	Parameter	Norm		Unit
		Min	Max	
U <sub>CC</sub>	Supply voltage	4,75	9	V
U <sub>08</sub>	Voltage applied to closed output, V (pin 08)	-	15	V
T <sub>a</sub>	Operating ambient temperature	0	70	°C

**Table 4 – Electric parameters**

Parameter, unit, mode of measurement	Symbol	Norm		Ambient temperature, °C
		Min	Max	
Quiescent consumption current, mA at $U_{CC} = 5\text{ V}$ , $R_L = 20\text{ k}\Omega$	$I_{CC}$	-	$\frac{8}{9}$	$\frac{25 \pm 10}{0; 70}$
Dynamic consumption current, mA at $U_{CC} = 5\text{ V}$ , $R_L = 20\text{ k}\Omega$	$I_{OCC}$	-	$\frac{13}{14}$	
Input resistance, $k\Omega$ $U_{CC} = 5\text{ V}$	$R_I$	$\frac{15}{14}$	-	
Smallest detectable input voltage, mV (RMS) at $U_{CC} = 5\text{ V}$ , $I_L = 100\text{ mA}$ , $f_I = f_C$	$U_{Imin}$	-	$\frac{25}{30}$	
Largest detectable input voltage (at signal absence), mV (RMS) at $U_{CC} = 5\text{ V}$ , $I_L = 100\text{ mA}$ , $f_I = f_C$	$U_{Imax}$	$\frac{10}{9}$	-	
Bandwidth, % (relatively to central frequency $f_C$ )	BW	$\frac{10}{9}$	$\frac{18}{19}$	
Bandwidth relative deviation, % (relatively to central frequency $f_C$ ) at $U_{CC} = 5\text{ V}$	$\Delta BW_{REL}$	-	$\frac{3,0}{3,5}$	
Coefficient of bandwidth variation with supply voltage, % / V at $U_{CC} = (4,75 - 6,75)\text{ V}$	$K_{BW}$	-	$\frac{\pm 5}{\pm 5,5}$	
Highest center frequency, kHz at $U_{CC} = 5\text{ V}$ , $R = 2,8\text{ k}\Omega$ , $C = 3300\text{ pF}$	$f_C$	$\frac{100}{110}$	-	
at $U_{CC} = 5\text{ V}$ , $R = 2,8\text{ k}\Omega$ , $C = 800\text{ pF}$		-	$\frac{500}{400}$	
Center frequency variation with supply voltage, %/V at $U_{CC} = (4,75 - 6,75)\text{ V}$ at $U_{CC} = (4,75 - 9,0)\text{ V}$	$\delta_{fC}$	-	$\frac{2,0}{2,5}$	
High level output leakage current, $\mu\text{A}$ at $U_{CC} = 5\text{ V}$ , $U_{O8} = 15\text{ V}$	$I_{OLH}$	-	$\frac{25}{40}$	
Output saturation voltage, V at $U_{CC} = 5; 9\text{ V}$ , $I_{O8}^{1)} = 30\text{ mA}$ , $U_{O3} = 25\text{ mV}$	$U_{OSAT}$	-	$\frac{0,4}{0,6}$	
at $U_{CC} = 5; 9\text{ V}$ , $I_{O8} = 100\text{ mA}$ , $U_{O3} = 25\text{ mV}$		-	$\frac{1,0}{1,5}$	
<sup>1)</sup> $I_{O8}$ – 08 pin current				

**Table 5 – Reference parameters**

Parameter, unit, mode of measurement	Symbol	Norm		Ambient temperature, °C
		Min	Max	
Largest Simultaneous Outband Signal to Inband Signal Ratio, dB	$N_s$	$\frac{1,5}{1,0}$	$\frac{9}{8}$	$\frac{25 \pm 10}{0}; 70$
Minimum Input Signal to Wideband Noise Ratio, dB at $U_{CC} = 5\text{ V}$ , $B_n = 140\text{ kHz}$	$N_n$	$\frac{-1,5}{-1,0}$	$\frac{-9}{-8}$	
Cycle repeating frequency, kHz at $U_{CC} = 5\text{ V}$	$f_{cyc}$	-	$\frac{f_c/20}{f_c/25}$	
Output fall time, ns at $U_{CC} = 5\text{ V}$	$t_f$	-	$\frac{60}{80}$	
Output rise time, ns at $U_{CC} = 5\text{ V}$	$t_r$	-	$\frac{300}{350}$	
Coefficient of bandwidth variation with temperature, % / °C at $U_{CC} = 5\text{ V}$	$\alpha_{BW}$	-	$\pm 0,2$	0; 70
Coefficient of central frequency variation with temperature, ppm/°C at $U_{CC} = (4,75 - 5,75)\text{ B}$	$\alpha_{fc}$	-100	100	0; 70

### Functionality of the microcircuit

Tone signals decoder IC is purposed for decoding of frequencies in bandwidth BW (relatively the central frequency), %, determined by expression

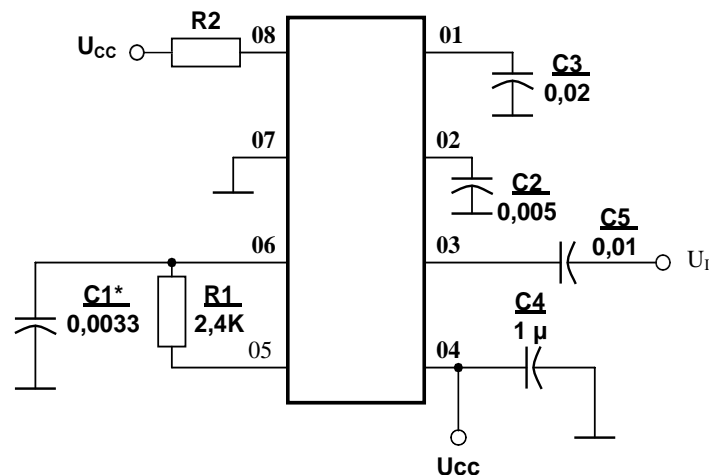
$$BW = 1070 \sqrt{\frac{U_i}{f_c C_2}}, \quad (2)$$

$U_i$  - input voltage (RMS)  $U_i \leq 200$  mV;

$f_c$  – bandwidth central frequency of decoder, kHz, is determined by formula

$$f_c \cong \frac{1}{1.1 R_1 C_1}, \quad (3)$$

$R_1, C_1, C_2$  - external passive components.



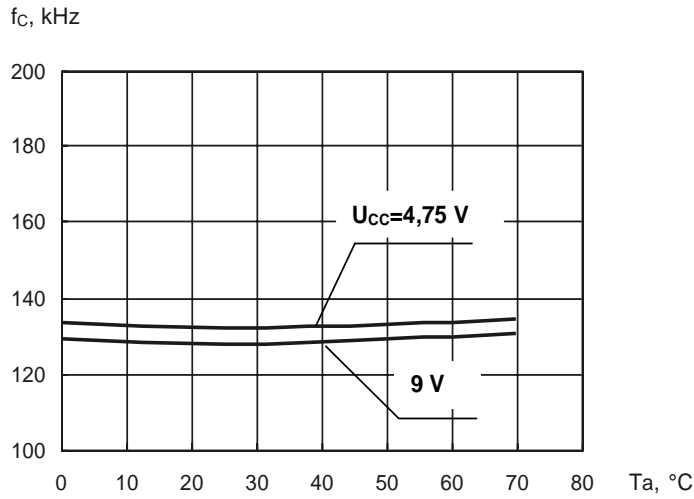
R2 – load resistor

\* for frequency  $f_c = 100$  kHz only.

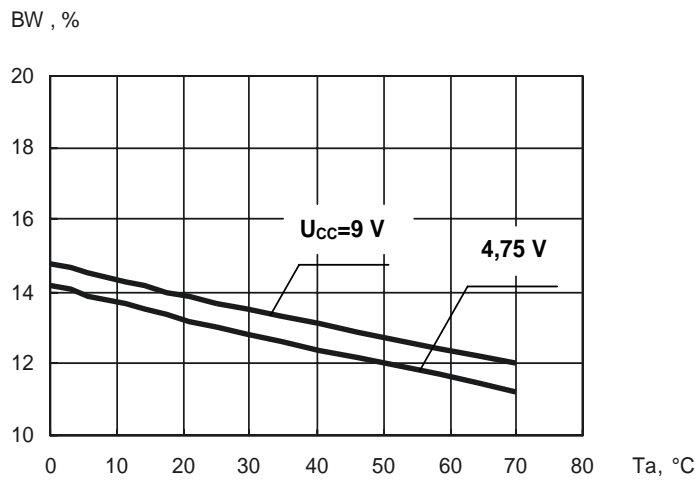
Capacitor C1 used to correct oscillator central frequency.  
 Capacitor C2 used to determine decoder bandwidth.

**Fig. 4 – Recommended application diagram**

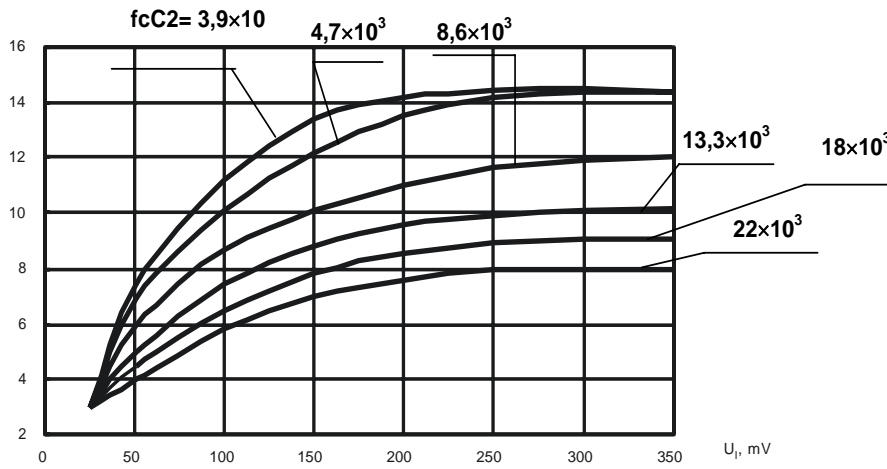
**Reference diagramm**



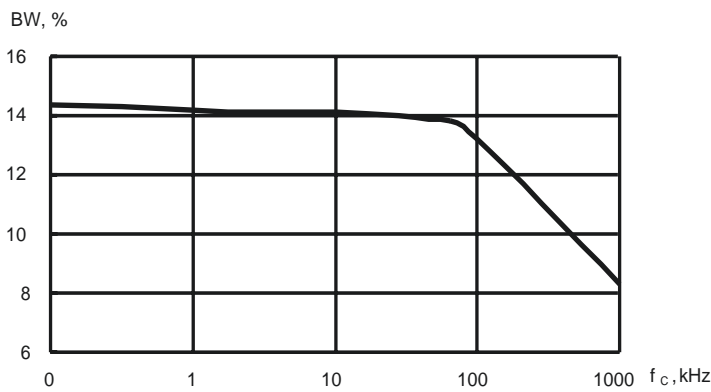
**Fig. 5 – Bandwidth central frequency average values versus ambient temperature**



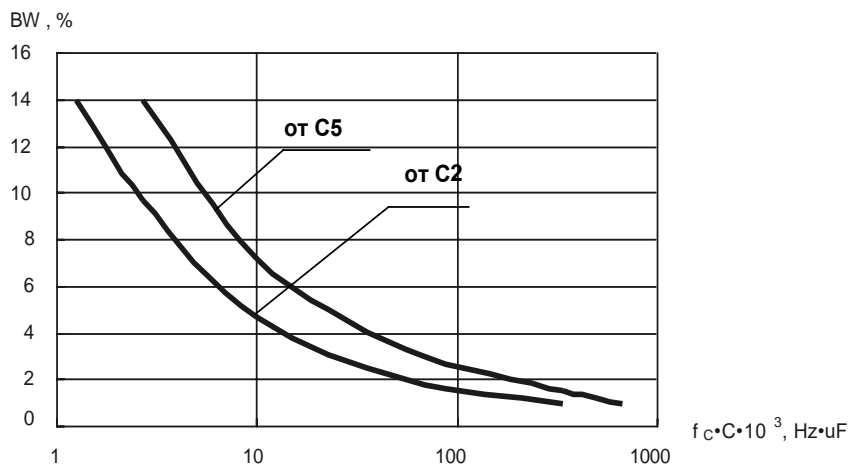
**Fig. 6 – Bandwidth average values versus ambient temperature**



**Fig. 7 Bandwidth average values versus input voltage at  $U_{CC}=5\text{ V}$ ,  $T_a = (25 \pm 10)^\circ\text{C}$**

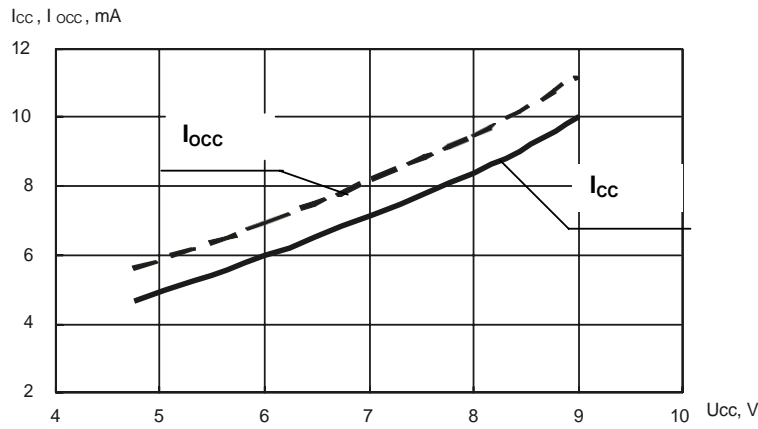


**Fig. 8 Bandwidth average values versus central frequency at  $U_{CC}=5\text{ V}$ ,  $T_a = (25 \pm 10)^\circ\text{C}$**

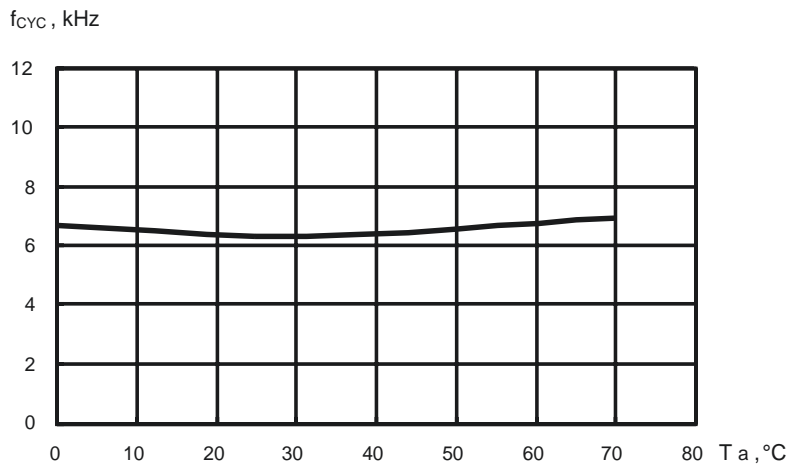


**Fig. 9 – Bandwidth average values versus capacity at  $U_{CC}=5\text{ V}$ ,  $T_a = (25 \pm 10)^\circ\text{C}$**

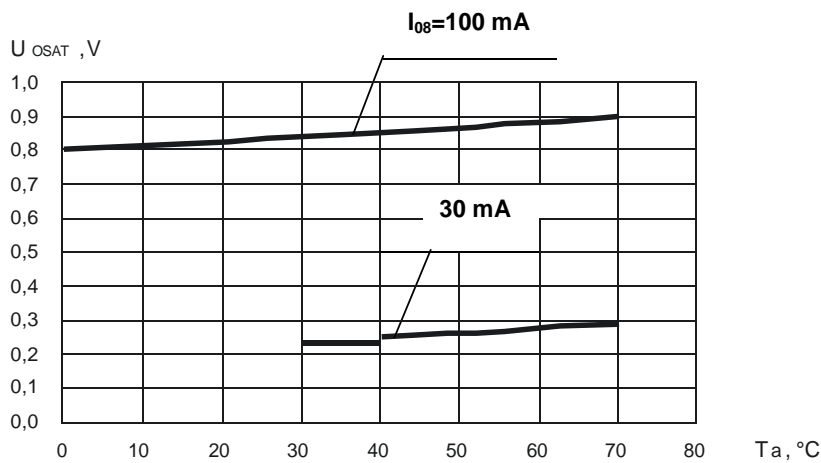




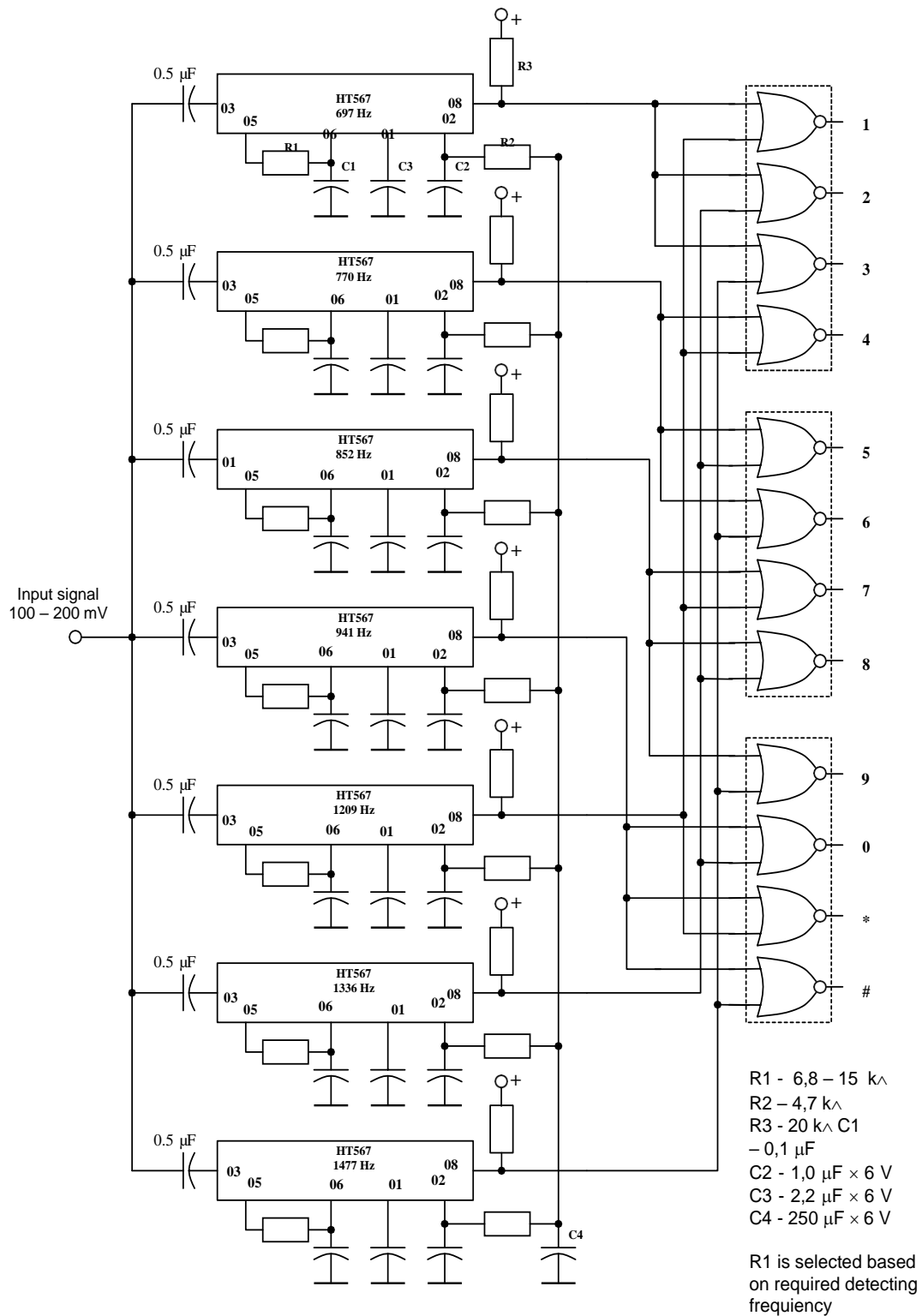
**Fig.10 – Quiescent consumption current and dynamic consumption current average values versus supply voltage  $T_a = (25\pm 10)^\circ C$**

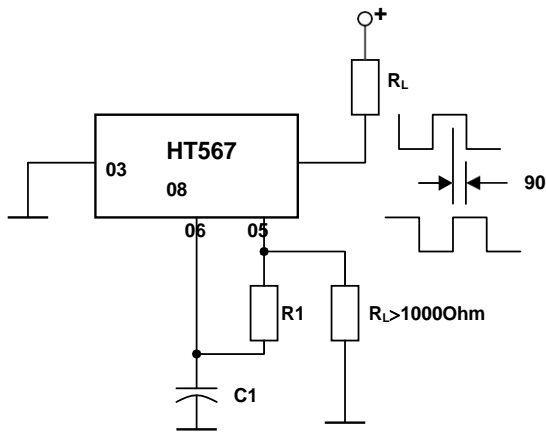


**Fig. 11 – Cycle repeating frequency average values versus ambient temperature at  $U_{CC}= 5 V$**



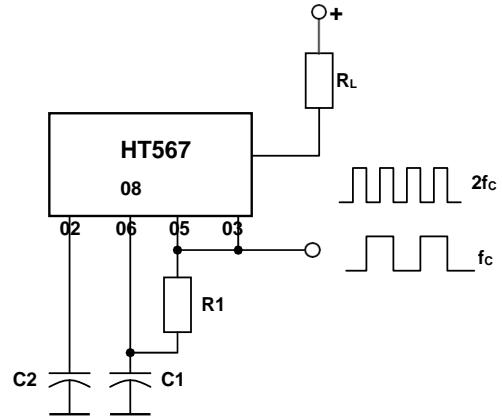
**Fig. 12 – Output saturation voltage average values versus ambient temperature at  $U_{CC}= 5 V$**

**Typical applications diagrams**

**Fig.13 - Push-button phone decoder**

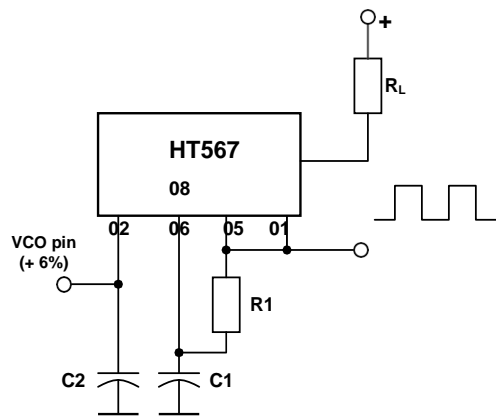


Output signal is inverted at 2.8V voltage applied to pin 03.

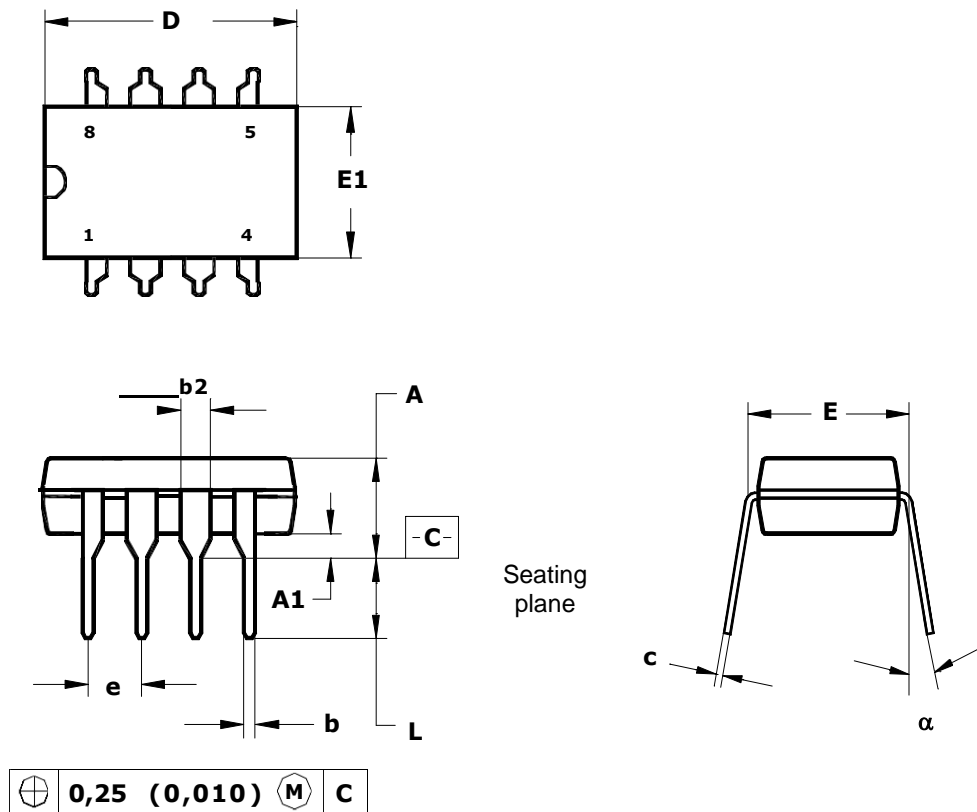
**Fig. 14 - Oscillator with Quadrature Output**



**Fig. 15 - Oscillator with Double Frequency Output**



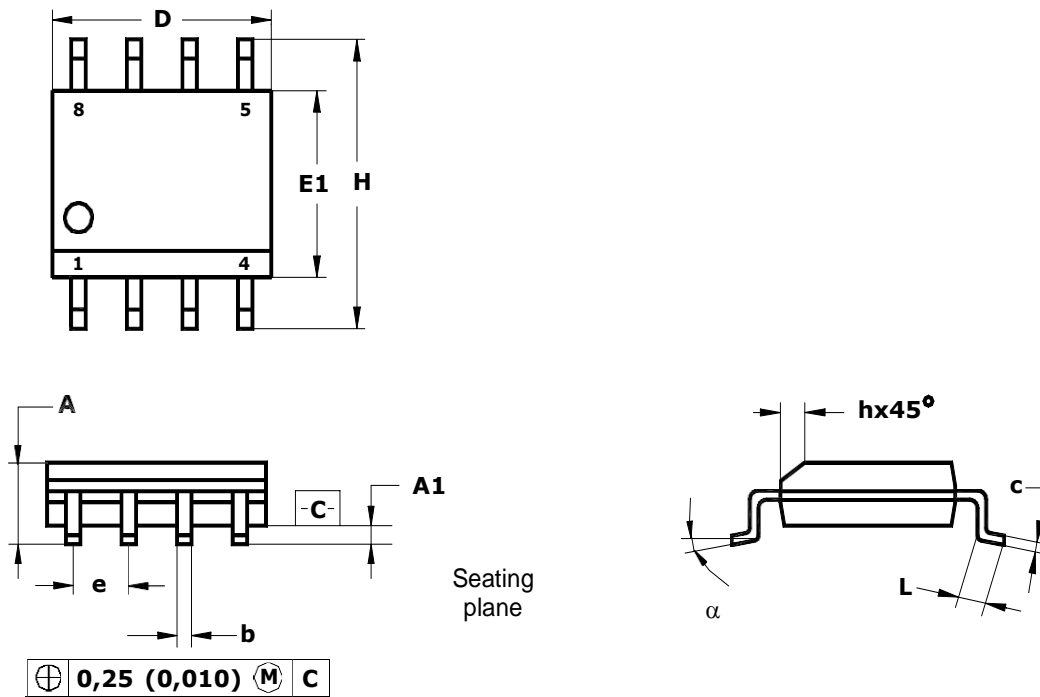
**Fig. 16 - Precision oscillator-driver with 100 mA load**



Note – The sizes D, E1 do not include size of the spew which should not be more 0,25 (0,010) on the side.

	D	E1	A	b	b2	e	$\alpha$	L	E	c	A1
mm											
min	9.02	6.07	↓	0.36	1.14		0°	2.93	7.62	0.20	0.38
max	10.16	7.11	5.33	0.56	1.78	2.54	15°	3.81	8.26	0.36	↓
inches											
min	0.355	0.240	↓	0.014	0.045		0°	0.115	0.300	0.008	0.015
max	0.400	0.280	0.210	0.022	0.070	0.1	15°	0.150	0.325	0.014	↓

**Fig. 17 – DIP-packade (MS-001BA) dimensions**



	D	E1	H	b	e	$\alpha$	A	A1	c	L	h
mm											
min	4.80	3.80	5.80	0.33		0°	1.35	0.10	0.19	0.41	0.25
max	5.00	4.00	6.20	0.51	1.27	8°	1.75	0.25	0.25	1.27	0.50
inches											
min	0.1890	0.1497	0.2284	0.013		0°	0.0532	0.0040	0.0075	0.016	0.0099
max	0.1968	0.1574	0.2440	0.020	0.100	8°	0.0688	0.0090	0.0098	0.050	0.0196

**Fig. 18 – SO- package (MS-012AA) dimensions**

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